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STMicroelectronics STPS640CBY-TR

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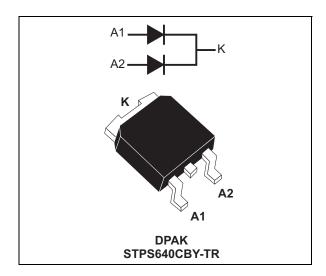




STPS640C-Y

Automotive power Schottky rectifier

Datasheet - production data



Features

- Low forward voltage drop
- · Very small conduction losses
- Negligible switching losses
- · Extremely fast switching
- Low thermal resistance
- · AEC-Q101 qualified.

Description

This dual Schottky rectifier is designed for switch mode power supplies and other power converters.

This device is intended for use in low and medium voltage operation, and in particular high frequency circuits where low switching losses are required (free wheeling and polarity protection) in automotive applications.

Table 1. Device summary

Symbol	Value
I _{F(AV)}	2 x 3 A
V _{RRM}	40 V
T _j	150 °C
V _{F (Typ)}	0.50 V



Characteristics STPS640C-Y

1 Characteristics

Table 2. Absolute ratings (limiting values, per diode)

Symbol	Parameter			Value	Unit
V_{RRM}	Repetitive peak reverse voltage			40	V
I _{F(RMS)}	Forward rms current			6	Α
	per diode		3	Α	
$I_{F(AV)}$ Average forward current, $\delta = 0.5$, $T_c = 135$ °C		Ī	per device	6	
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}, T_c = 25 ^{\circ}\text{C}$			75	Α
I _{RRM}	Peak repetitive reverse current $t_p = 2 \mu s$, $F = 1 kHz$			1	Α
P _{ARM}	Repetitive peak avalanche power $t_p = 1 \mu s, T_c = 25 ^{\circ}C$			1300	W
T _{stg}	Storage temperature range			-65 to +150	°C
T _j	Operating junction temperature			-40 to +150	°C

Table 3. Thermal parameters

Symbol	Parameter	Value	Unit	
D	Junction to case per diode	!	5.5	
R _{th(j-c)}	per devic	е	3	°C/W
R _{th(c)}	coupling		0.5	

When the diodes 1 and 2 are used simultaneously : $\Delta Tj(diode\ 1) = P(diode\ 1) \times R_{th(j-c)}(Per\ diode) + P(diode\ 2) \times R_{th(c)}$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I _R ⁽¹⁾ Reverse leakage current	T _j = 25 °C	\/ _\/	-	-	100	μΑ	
'R'	I _R ⁽¹⁾ Reverse leakage current	T _j = 125 °C	$V_R = V_{RRM}$	-	2	10	mA
	V _F ⁽²⁾ Forward voltage drop	T _j = 25 °C	I _F = 3 A	-	-	0.63	V
V (2)		T _j = 125 °C		-	0.50	0.57	
VF` ′		T _j = 25 °C	I _F = 6 A	-	-	0.84	V
		T _j = 125 °C		-	0.67	0.72	

- 1. Pulse test: $t_p = 5 \text{ ms}$, $\delta < 2\%$
- 2. Pulse test: t_p = 380 μ s, δ < 2%

To evaluate the conduction losses use the following equation:

$$P = 0.42 \times I_{F(AV)} + 0.050 \times I_{F(RMS)}^{2}$$





STPS640C-Y Characteristics

Figure 1. Average forward power dissipation versus average forward current (per diode)

PF(AV)(W) 2.50 $\delta = 0.2 \pm \delta = 0.5$ δ = 1 2.25 $\delta = 0.1$ $\delta = 0.05$ 2.00 1.75 1.50 1.25 1.00 0.75 0.50 0.25 0.00 0.0 0.5 1.0 1.5 2.0 2.5 3.0 3.5 4.0

Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$, per diode)

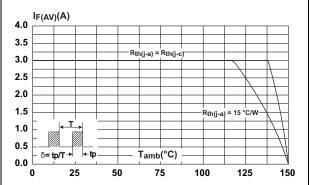
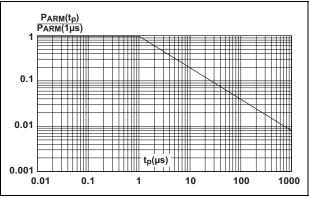


Figure 3. Normalized avalanche power derating versus pulse duration versus junction temperature



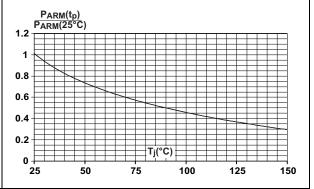
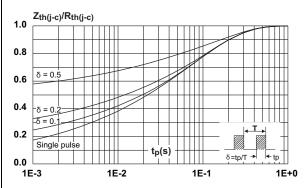
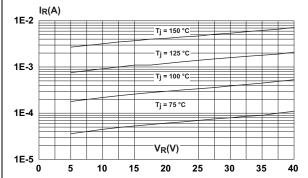


Figure 5. Relative variation of thermal impedance junction to case versus pulse duration

Figure 6. Reverse leakage current vs. reverse voltage applied (typical values, per diode)



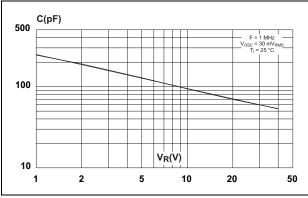




Characteristics STPS640C-Y

Figure 7. Junction capacitance vs. reverse voltage applied (typical values, per diode)

Figure 8. Forward voltage drop vs. forward current (per diode)



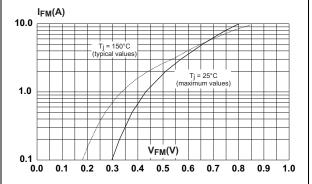
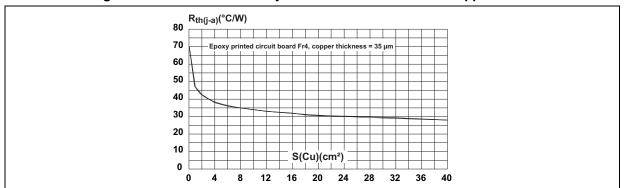


Figure 9. Thermal resistance junction to ambient versus copper surface under tab







STPS640C-Y Package information

2 Package information

- Epoxy meets UL94,V0
- Lead-free packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Figure 10. DPAK dimension definitions

E
B2
C2
A
C2
R
C2
O.60 MIN.

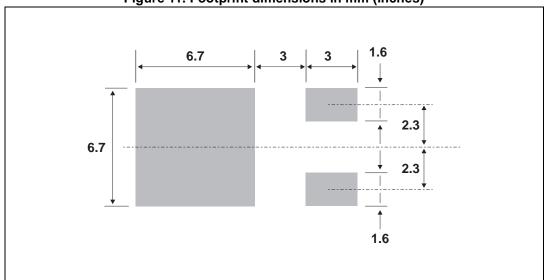


Package information STPS640C-Y

Table 5. DPAK dimension values

			Dimens	ions				
Ref.	Millimeters					Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α	2.20		2.40	0.086		0.094		
A1	0.90		1.10	0.035		0.043		
A2	0.03		0.23	0.001		0.009		
В	0.64		0.90	0.025		0.035		
B2	5.20		5.40	0.204		0.212		
С	0.45		0.60	0.017		0.023		
C2	0.48		0.60	0.018		0.023		
D	6.00		6.20	0.236		0.244		
Е	6.40		6.60	0.251		0.259		
G	4.40		4.60	0.173		0.181		
Н	9.35		10.10	0.368		0.397		
L2		0.80 typ.			0.031 typ.			
L4	0.60		1.00	0.023		0.039		
V2	0°		8°	0°		8°		

Figure 11. Footprint dimensions in mm (inches)





STPS640C-Y Ordering information

3 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	ty Delivery mode	
STPS640CBY-TR	STPS640CY	DPAK	0.3 g	2500	Tape and reel	

4 Revision history

Table 7. Revision history

Date	Revision	Changes	
6-Nov-2013	1	First issue	
04-Dec-2013	2	Properties changed from preliminary data to production data.	



Distributor of STMicroelectronics: Excellent Integrated System Limited Datasheet of STPS640CBY-TR - DIODE ARRAY SCHOTTKY 40V 3A DPAK

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